NSN 5961-01-469-0535

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-469-0535 **Inclosure Material:** Metal **Overall Length:** 0.410 inches **Overall Diameter:** 1.325 inches **End Application:** 6625-15-064-3505 test set electronics systems x925-501 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 14.0 regulator voltage **Current Rating Per Characteristic:** 890.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Special Features:** Same as 1n2812b but with different quality level **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.